DOUT2 3

ROUT2 5

DIN2

ROUT1

RIN1

DIN1 7

6

8

9

П

GND 10

V<sub>CC</sub> [ 11 C1+ [ 12

V+

C1-

П

13

14

RIN2  $\Pi$  4

DB, DW, OR PW PACKAGE

(TOP VIEW)

28 DOUT4

26 ROUT3

25 SHDN

24 🛛 EN

23 RIN4 22 ROUT4

21 DIN4

20 DIN3

18 RIN5

17 V-

16 C2-

15 C2+

19 ROUT5

27 RIN3

#### FEATURES

- ESD Protection for RS-232 Bus Pins – ±15-kV Human-Body Model (HBM)
- Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU v.28 Standards
- Operates at 5-V V<sub>CC</sub> Supply
- Four Drivers and Five Receivers
- Operates up to 120 kbit/s
- Low Supply Current in Shutdown Mode . . . 15 μA Typ
- External Capacitors . . . 4 × 0.1 F
- Designed to Be Interchangeable With Maxim MAX213
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II

#### **APPLICATIONS**

- Battery-Powered Systems
- PDAs
- Notebooks
- Laptops
- Palmtop PCs
- Hand-Held Equipment

#### **DESCRIPTION/ ORDER INFORMATION**

The MAX213 device consists of four line drivers, five line receivers, and a dual charge-pump circuit with  $\pm$ 15-kV ESD protection pin to pin (serial-port connection pins, including GND). The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 5-V supply. The devices operate at data signaling rates up to 120 kbit/s and a maximum of 30-V/µs driver output slew rate.

The MAX213 has an active-low shutdown (SHDN) and an active-high enable control (EN). In shutdown mode, the charge pumps are turned off, V+ is pulled down to  $V_{CC}$ , V– is pulled to GND, and the transmitter outputs are disabled. This reduces supply current typically to 1  $\mu$ A. Two receivers of the MAX213 are active during shutdown.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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#### **ORDERING INFORMATION**

T <sub>A</sub>	PAC	KAGE <sup>(1)</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	SOIC – DW	Tube of 20	MAX213CDW	
	50IC - DW	Reel of 1000	MAX213CDWR	
0°C to 70°C		Tube of 50	MAX213CDB	
	SSOP – DB	Reel of 2000	MAX213CDBR	
	TSSOP – PW	Tape and reel	MAX213CPWR	
	SOIC – DW	Tube of 20	MAX213IDW	
	50IC - DW	Reel of 1000	MAX213IDWR	
–40°C to 85°C	SSOP – DB	Tube of 50	MAX213IDB	
	220h - DR	Reel of 2000	MAX213IDBR	
	TSSOP – PW	Tape and reel	MAX213IPWR	

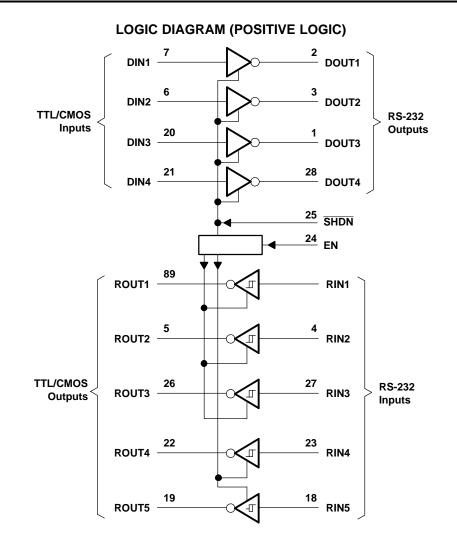
(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

#### **FUNCTION TABLE**

INP	UTS	DRIVER	REC	EIVER	DEVICE STATUS
SHDN	EN	D1–D4	R1–R3	R4–R5	DEVICE STATUS
L	L	Z	Z	Z	Shutdown
L	Н	Z	Z	Active <sup>(1)</sup>	Shutdown
Н	L	All active	Z	Z	Normal operation
Н	Н	All active	Active	Active	Normal operation

(1) See the  $V_{IT+}$  and  $V_{IT-}$  change in the *Electrical Characteristics* table.

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## Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT		
V <sub>CC</sub>	Supply voltage range		-0.3	6	V		
V+	Positive charge-pump voltage range <sup>(2)</sup>		V <sub>CC</sub> – 0.3	14	V		
V–	Negative charge-pump voltage range <sup>(2)</sup>		0.3	-14	V		
N/		Drivers	-0.3	V+ + 0.3	N		
VI	Input voltage range	Receivers		±30	V		
		Drivers	V0.3	V+ + 0.3			
Vo	Output voltage range	Receivers	-0.3	V <sub>CC</sub> + 0.3	V		
DOUT	Short-circuit duration		C	Continuous			
		DB package		62			
$\theta_{JA}$	Package thermal impedance <sup>(3)(4)</sup>	DW package		46	C°/W		
		PW package					
TJ	Operating virtual junction temperature		150	C°			
T <sub>stg</sub>	Storage temperature range	-65	150	C°			

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

All voltages are with respect to network GND. (2)

Maximum power dissipation is a function of  $T_J(max), \theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient (3) temperature is  $P_D = (T_J(max) - T_A)/\theta_{JA}$ . Operating at the absolute maximum  $T_J$  of 150°C can affect reliability. The package thermal impedance is calculated in accordance with JESD 51-7.

(4)

## Recommended Operating Conditions<sup>(1)</sup>

#### See Figure 4

			MIN	NOM	MAX	UNIT
	Supply voltage		4.5	5	5.5	V
v	Driver high-level input voltage	DIN	2			V
V <sub>IH</sub>	Control high-level input voltage EN, SHDN					v
VIL	Driver and control low-level input voltage	DIN, EN, SHDN			0.8	V
v	Driver and control input voltage DIN, EN, SHDN		0		5.5	V
VI	Receiver input voltage	RIN	-30		30	v
т	Operating free air temperature	MAX213C	0		70	°C
IA	Operating free-air temperature MAX213I				85	C

(1) Test conditions are C1–C4 = 0.1  $\mu F$  at V<sub>CC</sub> = 5 V  $\pm$  0.5 V.

#### Electrical Characteristics<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	٢	MIN	TYP <sup>(2)</sup>	MAX	UNIT	
I <sub>CC</sub>	Supply current	No load,	See Figure 6		14	20	mA
I <sub>SHDN</sub>	Shutdown supply current	$T_A = 25^{\circ}C$ ,	See Figure 1		15	50	μA

Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 5 V ± 0.5 V. (1)

(2) All typical values are at  $V_{CC} = 5$  V, and  $T_A = 25^{\circ}C$ .

#### **DRIVER SECTION**

## Electrical Characteristics<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted) (see Figure 4)

	PARAMETER	TEST CONDI	TEST CONDITIONS			MAX	UNIT
V <sub>OH</sub>	High-level output voltage	DOUT at $R_L = 3 k\Omega$ to GNE	DOUT at $R_L = 3 \text{ k}\Omega$ to GND				V
V <sub>OL</sub>	Low-level output voltage	DOUT at $R_L = 3 k\Omega$ to GNI	כ	-5	-9		V
I <sub>IH</sub>	Control high-level input current	EN, <u>SHDN</u> = 5 V			3	10	μA
	Driver low-level input current	DIN = 0 V			-15	-200	
ΙL	Control low-level input current	EN, <u>SHDN</u> = 0 V			-3	-10	μA
$I_{OS}^{(3)}$	Short-circuit output current	V <sub>CC</sub> = 5.5 V,	$V_0 = 0 V$		±10	±60	mA
r <sub>o</sub>	Output resistance	$V_{CC}$ , V+, and V- = 0 V,	$V_0 = \pm 2 V$	300			Ω

(1)

(2)

Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 5 V ± 0.5 V All typical values are at V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C. Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one (3) output should be shorted at a time.

## Switching Characteristics<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CO	NDITIONS	MIN	TYP <sup>(2)</sup>	MAX	UNIT
	Maximum data rate			120			kbit/s
t <sub>PLH(D)</sub>	Propagation delay time, low- to high-level output	C <sub>L</sub> = 2500 pF, All drivers loaded,	$R_L = 3 k\Omega$ , See Figure 3		2		μs
t <sub>PHL(D)</sub>	Propagation delay time, high- to low-level output	C <sub>L</sub> = 2500 pF, All drivers loaded,	$R_L = 3 k\Omega$ , See Figure 3		2		μs
t <sub>sk(p)</sub>	Pulse skew <sup>(3)</sup>	$C_L = 150 \text{ pF}$ to 2500 pF, See Figure 3	$R_L = 3 k\Omega$ to 7 k $\Omega$ ,	300		ns	
SR(tr)	Slew rate, transition region (see Figure 2)			3	6	30	V/µs

(1)

(2)

Test conditions are C1–C4 = 0.1  $\mu F$  at V<sub>CC</sub> = 5 V  $\pm$  0.5 V. All typical values are at V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C. Pulse skew is defined as (t<sub>PLH</sub> - t<sub>PHL</sub>) of each channel of the same device. (3)

#### **ESD** Protection

over operating free-air temperature range (unless otherwise noted)

PIN	TEST CONDITIONS	TYP	UNIT
DOUT	Human-Body Model	±15	kV

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#### **RECEIVER SECTION**

#### Electrical Characteristics<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted) (see Figure 6)

	PARAMETER	TEST	CONDITIONS	MIN	TYP <sup>(2)</sup>	MAX	UNIT
V <sub>OH</sub>	High-level output voltage	$I_{OH} = -1 \text{ mA}$			$V_{CC} - 0.4$		V
V <sub>OL</sub>	Low-level output voltage	I <sub>OH</sub> = 1.6 mA			0.4	V	
V	Positive-going	$V_{CC} = 5 V, T_{A} = 25^{\circ}C$	Active mode		1.7	2.4	V
V <sub>IT+</sub>	input threshold voltage	$v_{\rm CC} = 5 v, T_{\rm A} = 25 C$	Shutdown mode (R4-R5)		1.5	2.4	v
	Negative-going		Active mode	0.8	1.2		V
V <sub>IT</sub>	input threshold voltage	$V_{CC} = 5 V, T_A = 25^{\circ}C$	Shutdown mode (R4-R5)	0.6	1.5		v
Vhys <sup>(3)</sup>	Input hysteresis (V <sub>IT+</sub> , V <sub>IT-</sub> )	$V_{CC} = 5 V$			0.5	1	V
r <sub>l</sub>	Input resistance	$V_{CC} = 5 \text{ V}, \text{ T}_{A} = 25^{\circ}\text{C}$	3	5	7	kΩ	
	Output leakage current	$EN = 0 V, 0 \le ROUT \le V$	$EN = 0 V, 0 \le ROUT \le V_{CC}, R1-R3$				μA

## Switching Characteristics<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

	PARAMETER		TEST CONDITI	IONS	MIN	TYP <sup>(2)</sup>	MAX	UNIT
+	Propagation delay time,	C = 150  pc	Soo Figuro 4	$\overline{\text{SHDN}} = V_{CC}$		0.5	10	
t <sub>PLH(R)</sub>	low- to high-level output	C <sub>L</sub> = 150 pF,	See Figure 4	<u>SHDN</u> = 0 V, R4–R5		4	40	μs
t <sub>PHL(R)</sub>	Propagation delay time, high- to low-level output	C <sub>L</sub> = 150 pF,	See Figure 4			0.5	10	μs
t <sub>en</sub>	Output enable time	C <sub>L</sub> = 150 pF,	See Figure 5			600		ns
t <sub>dis</sub>	Output disable time	C <sub>L</sub> = 150 pF,	See Figure 5			200		ns

Test conditions are C1–C4 = 0.1  $\mu F$  at V<sub>CC</sub> = 5 V  $\pm$  0.5 V. All typical values are at V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C. (1)

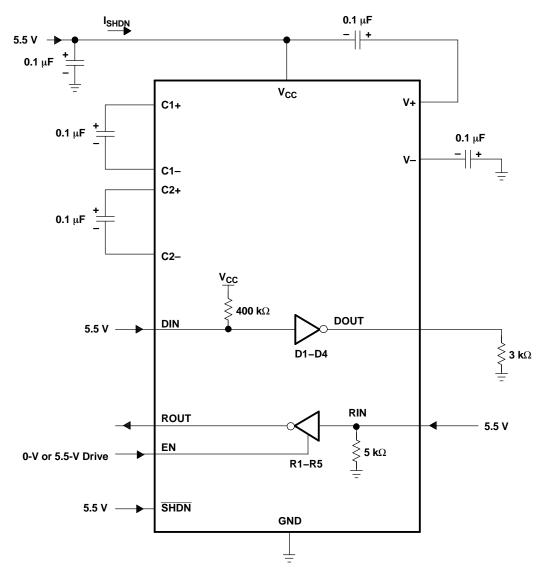
(2)

#### **ESD** Protection

over operating free-air temperature range (unless otherwise noted)

PIN	TEST CONDITIONS	TYP	UNIT
RIN	Human-Body Model	±15	kV

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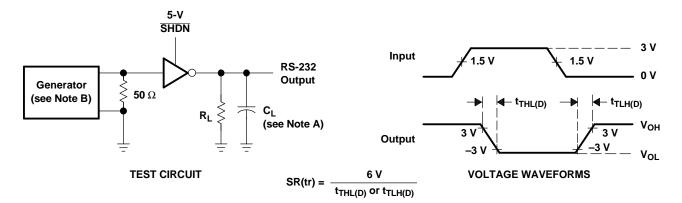
PARAMETER MEASUREMENT INFORMATION

Figure 1. Shutdown Current Test Circuit

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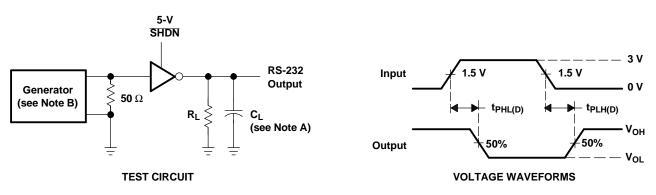
#### PARAMETER MEASUREMENT INFORMATION (continued)

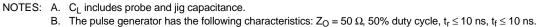


NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

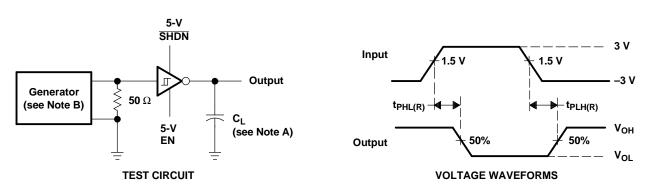
B. The pulse generator has the following characteristics:  $Z_0 = 50 \Omega$ , 50% duty cycle,  $t_r \le 10$  ns,  $t_f \le 10$  ns.

Figure 2. Driver Slew Rate





#### Figure 3. Driver Pulse Skew and Propagation Delay Times



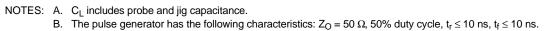
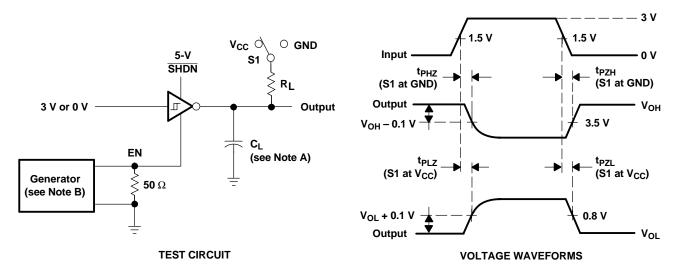


Figure 4. Receiver Propagation Delay Times



#### PARAMETER MEASUREMENT INFORMATION (continued)

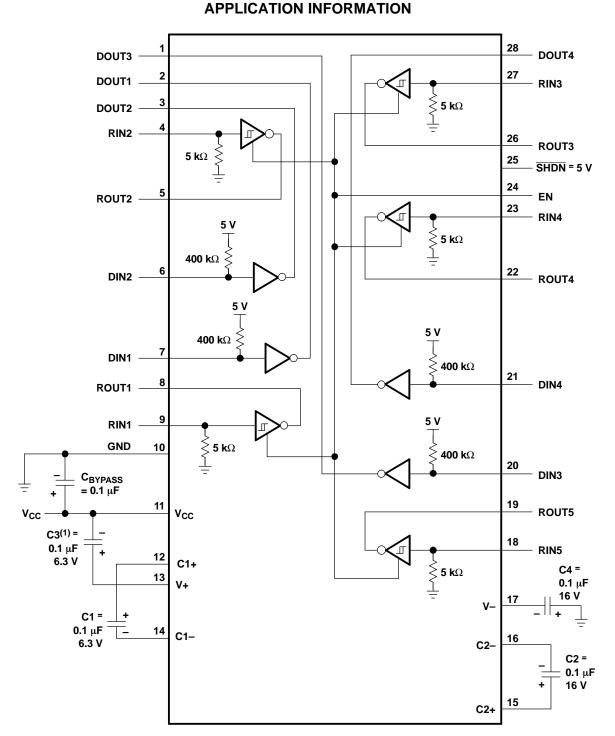


- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. The pulse generator has the following characteristics:  $Z_0 = 50 \Omega$ , 50% duty cycle,  $t_r \le 10$  ns,  $t_f \le 10$  ns.
  - C.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - D.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .

#### Figure 5. Receiver Enable and Disable Times

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(1) C3 can be connected to  $V_{\mbox{CC}}$  or GND.

- NOTES: A. Resistor values shown are nominal.
  - B. Nonpolarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown.





## PACKAGING INFORMATION

Orderable Device		Package Type	•	Pins	Package		Lead finish/	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	Ball material (6)	(3)		(4/5)	
MAX213CDB	ACTIVE	SSOP	DB	28	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	MAX213C	Samples
MAX213CDBR	ACTIVE	SSOP	DB	28	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	MAX213C	Samples
MAX213CDW	ACTIVE	SOIC	DW	28	20	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	MAX213C	Samples
MAX213CDWR	ACTIVE	SOIC	DW	28	1000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	MAX213C	Samples
MAX213IDB	ACTIVE	SSOP	DB	28	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MAX213I	Samples
MAX213IDBR	ACTIVE	SSOP	DB	28	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MAX213I	Samples
MAX213IDWR	ACTIVE	SOIC	DW	28	1000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	MAX213I	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <= 1000ppm threshold. Antimony trioxide based flame retardants must also meet the <= 1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



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# PACKAGE OPTION ADDENDUM

10-Dec-2020

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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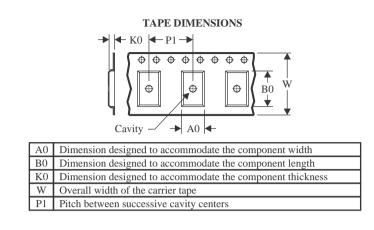


Texas

STRUMENTS

#### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



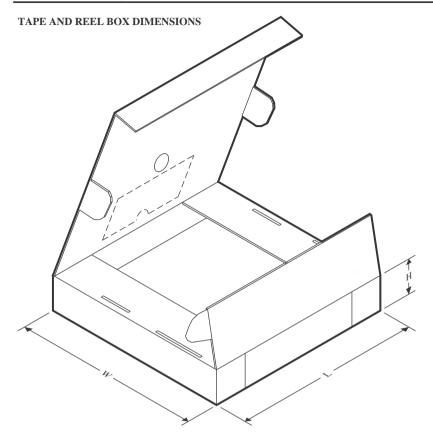
*All dimensions are nomina												t.
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
MAX213CDBR	SSOP	DB	28	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
MAX213CDWR	SOIC	DW	28	1000	330.0	32.4	11.35	18.67	3.1	16.0	32.0	Q1
MAX213IDBR	SSOP	DB	28	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
MAX213IDWR	SOIC	DW	28	1000	330.0	32.4	11.35	18.67	3.1	16.0	32.0	Q1



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# PACKAGE MATERIALS INFORMATION

3-Jun-2022



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
MAX213CDBR	SSOP	DB	28	2000	356.0	356.0	35.0
MAX213CDWR	SOIC	DW	28	1000	350.0	350.0	66.0
MAX213IDBR	SSOP	DB	28	2000	356.0	356.0	35.0
MAX213IDWR	SOIC	DW	28	1000	350.0	350.0	66.0

## TEXAS INSTRUMENTS

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3-Jun-2022

## TUBE



# - B - Alignment groove width

#### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
MAX213CDB	DB	SSOP	28	50	530	10.5	4000	4.1
MAX213CDW	DW	SOIC	28	20	506.98	12.7	4826	6.6
MAX213IDB	DB	SSOP	28	50	530	10.5	4000	4.1

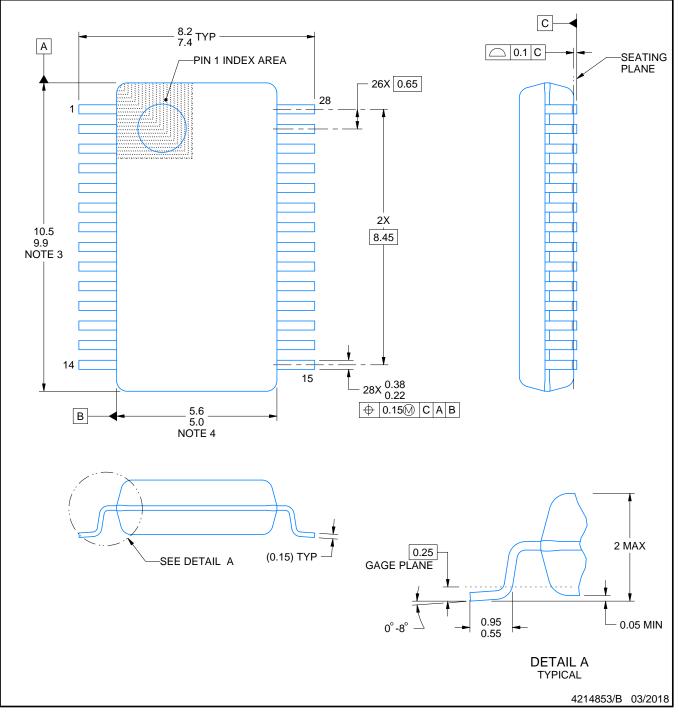
# **DB0028A**



# **PACKAGE OUTLINE**

# SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.

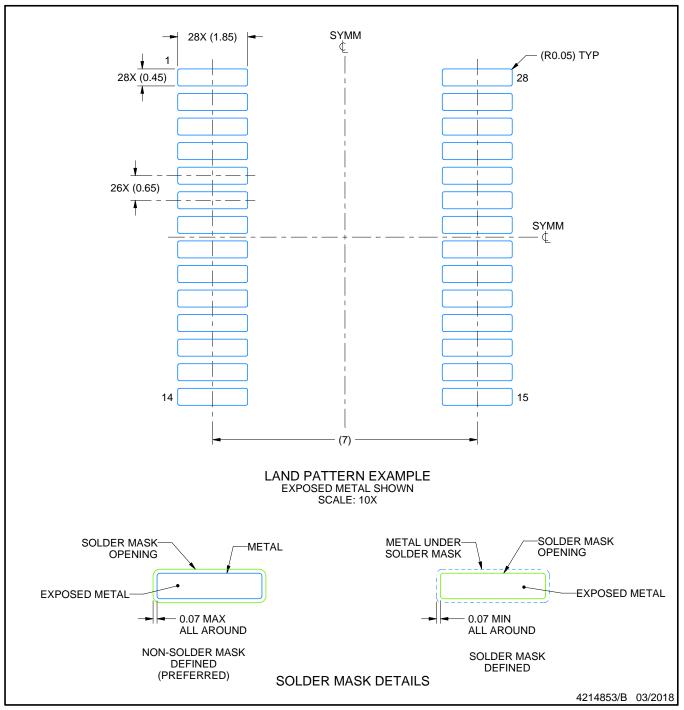


# DB0028A

# **EXAMPLE BOARD LAYOUT**

# SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

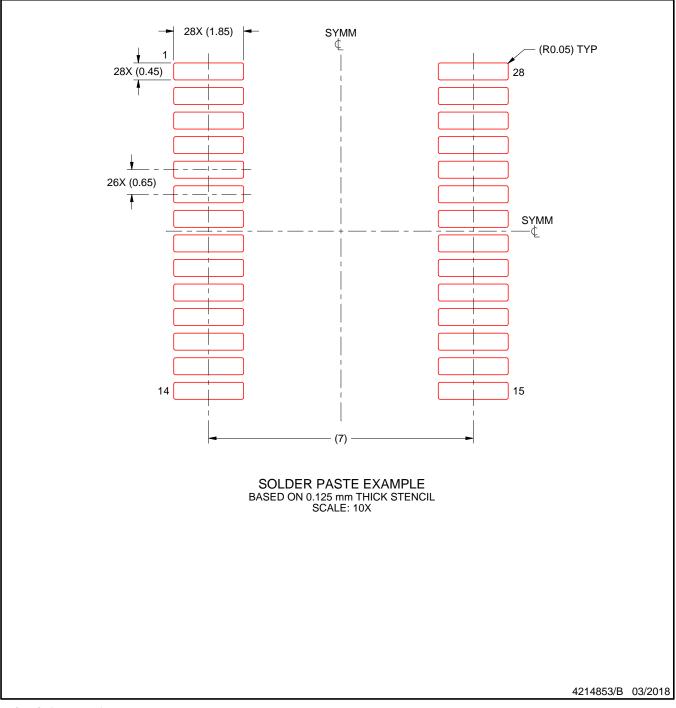


# DB0028A

# **EXAMPLE STENCIL DESIGN**

# SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

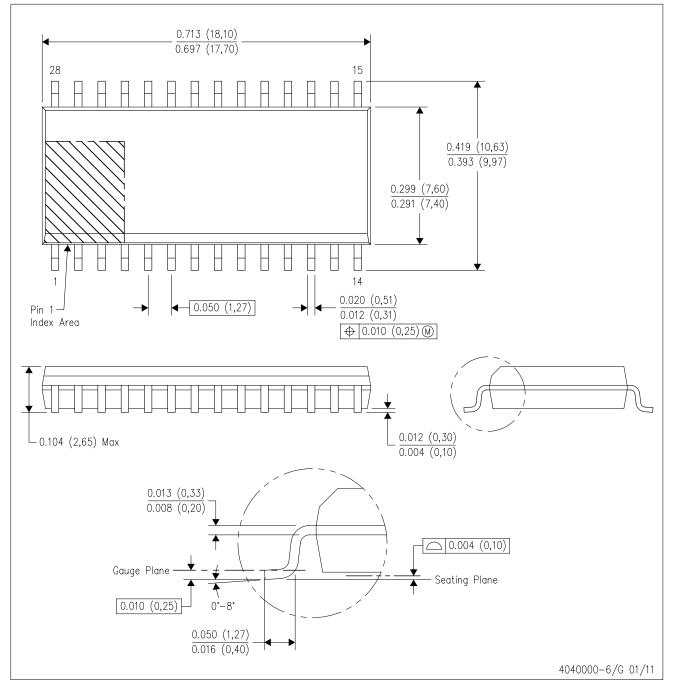
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



DW (R-PDSO-G28)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AE.



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